

Data Sheet January 2000 File Number 3933.2

30A, 400V - 600V Hyperfast Diodes

The RHRP3040 and RHRP3060 are hyperfast diodes with soft recovery characteristics (t_{rr} < 40ns). They have half the recovery time of ultrafast diodes and are of silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/ clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Formerly developmental type TA49063.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RHRP3040	TO-220AC	RHRP3040
RHRP3060	TO-220AC	RHRP3060

NOTE: When ordering, use the entire part number.

Symbol



Features

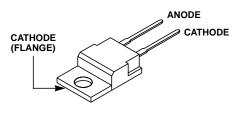
- · Avalanche Energy Rated
- Planar Construction

Applications

- · Switching Power Supplies
- · Power Switching Circuits
- · General Purpose

Packaging

JEDEC TO-220AC



Absolute Maximum Ratings T _C = 25°C, Unless Otherwise Specified			
	RHRP3040	RHRP3060	UNITS
Peak Repetitive Reverse VoltageV _{RRM}	400	600	V
Working Peak Reverse Voltage	400	600	V
DC Blocking VoltageV _R	400	600	V
Average Rectified Forward Current $I_{F(AV)}$ ($T_C = 120^{\circ}C$)	30	30	Α
Repetitive Peak Surge Current	70	70	Α
Nonrepetitive Peak Surge Current	325	325	Α
Maximum Power Dissipation	125	125	W
Avalanche Energy (See Figures 10 and 11)	20	20	mJ
Operating and Storage Temperature	-65 to 175	-65 to 175	οС

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

		RHRP3040		RHRP3060				
SYMBOL	TEST CONDITION	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
V _F	I _F = 30A	-	-	2.1	-	-	2.1	V
	I _F = 30A, T _C = 150°C	-	-	1.7	-	-	1.7	V
I _R	V _R = 400V	-	-	250	-	-	-	μА
	V _R = 600V	-	-	-	-	-	250	μА
	V _R = 400V, T _C = 150°C	-	-	1.0	-	-	-	mA
	$V_R = 600V, T_C = 150^{\circ}C$	-	-	-	-	-	1.0	mA
t _{rr}	I _F = 1A, dI _F /dt = 200A/μs	-	-	40	-	-	40	ns
	$I_F = 30A$, $dI_F/dt = 200A/\mu s$	-	-	45	-	-	45	ns
t _a	$I_F = 30A$, $dI_F/dt = 200A/\mu s$	-	22	-	-	22	-	ns
t _b	$I_F = 30A$, $dI_F/dt = 200A/\mu s$	-	18	-	-	18	-	ns
Q _{RR}	$I_F = 30A$, $dI_F/dt = 200A/\mu s$	-	100	-	-	100	-	nC
CJ	V _R = 10V, I _F = 0A	-	85	-	-	85	-	pF
R _{OJC}		-	-	1.2	-	-	1.2	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

 I_R = Instantaneous reverse current .

 t_{rr} = Reverse recovery time (See Figure 9), summation of $t_a + t_b$.

 t_a = Time to reach peak reverse current (See Figure 9).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

Q_{RR} = Reverse recovery charge.

C_J = Junction Capacitance.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

Typical Performance Curves

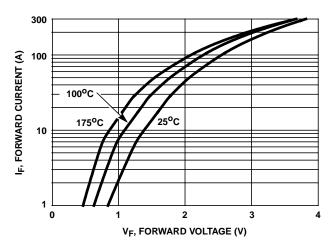


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

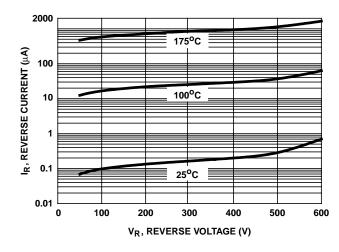


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

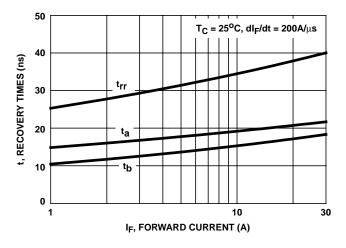


FIGURE 3. t_{rr} , t_a and t_b curves vs forward current

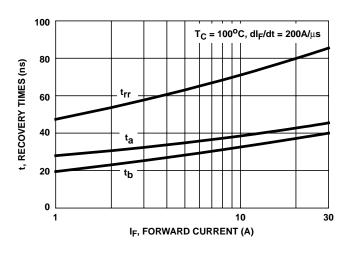


FIGURE 4. t_{rr} , t_a and t_b curves vs forward current

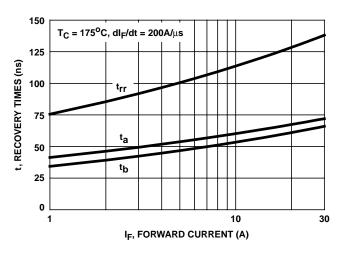


FIGURE 5. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

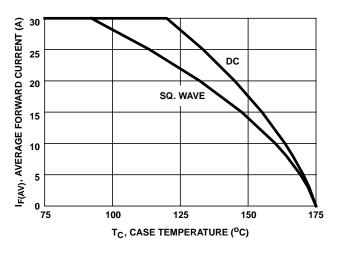


FIGURE 6. CURRENT DERATING CURVE

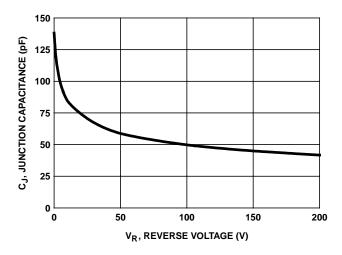


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuits and Waveforms

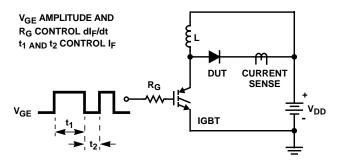


FIGURE 8. t_{rr} TEST CIRCUIT

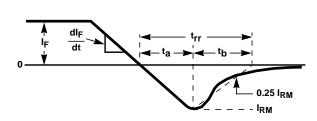


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

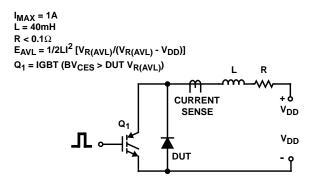


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

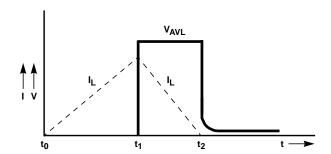


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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